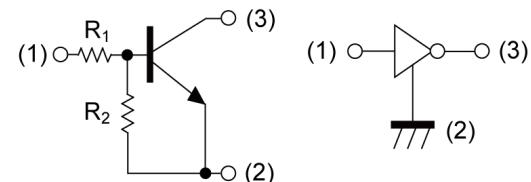
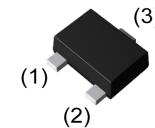


NPN 100mA 50V Digital Transistor (Bias Resistor Built-in Transistor)

## ●Features

- 1) Built-In Biasing Resistors,  
 $R_1 = 1\text{k}\Omega$ ,  $R_2 = 10\text{k}\Omega$
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) Only the on/off conditions need to be set for operation, making the circuit design easy.

SOT-723



(1) IN (BASE)  
(2) GND (EMITTER)  
(3) OUT (COLLECTOR)

## ●Application

INVERTER, INTERFACE, DRIVER

MARKING: E21

Parameter	Value
$V_{CC}$	50V
$I_C(\text{MAX.})$	100mA
$R_1$	1.0k $\Omega$
$R_2$	10k $\Omega$

## Absolute maximum ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Values	Unit
Supply voltage	$V_{CC}$	50	V
Input voltage	$V_{IN}$	-5 to 10	V
Output current	$I_O$	100	mA
Collector current	$I_C(\text{MAX.})^{\ast 1}$	100	mA
Power dissipation	$P_D^{\ast 2}$	150	mW
Junction temperature	$T_j$	150	°C
Range of storage temperature	$T_{stg}$	-55 to +150	°C

**Electrical characteristics ( $T_a = 25^\circ\text{C}$ )**

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input voltage	$V_{I(\text{off})}$	$V_{CC} = 5\text{V}, I_O = 100\mu\text{A}$	-	-	0.3	V
	$V_{I(\text{on})}$	$V_O = 0.3\text{V}, I_O = 20\text{mA}$	3.0	-	-	
Output voltage	$V_{O(\text{on})}$	$I_O = 10\text{mA}, I_I = 0.5\text{mA}$	-	100	300	mV
Input current	$I_I$	$V_I = 5\text{V}$	-	-	7.2	mA
Output current	$I_{O(\text{off})}$	$V_{CC} = 50\text{V}, V_I = 0\text{V}$	-	-	500	nA
DC current gain	$G_I$	$V_O = 5\text{V}, I_O = 5\text{mA}$	33	-	-	-
Input resistance	$R_1$	-	0.7	1.0	1.3	kΩ
Resistance ratio	$R_2/R_1$	-	8	10	12	-
Transition frequency	$f_T^{*1}$	$V_{CE} = 10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$	-	250	-	MHz

\*1 Characteristics of built-in transistor

\*2 Each terminal mounted on a reference land.

**Electrical characteristic curves ( $T_a = 25^\circ\text{C}$ )**

Fig.1 Input voltage vs. output current (ON characteristics)

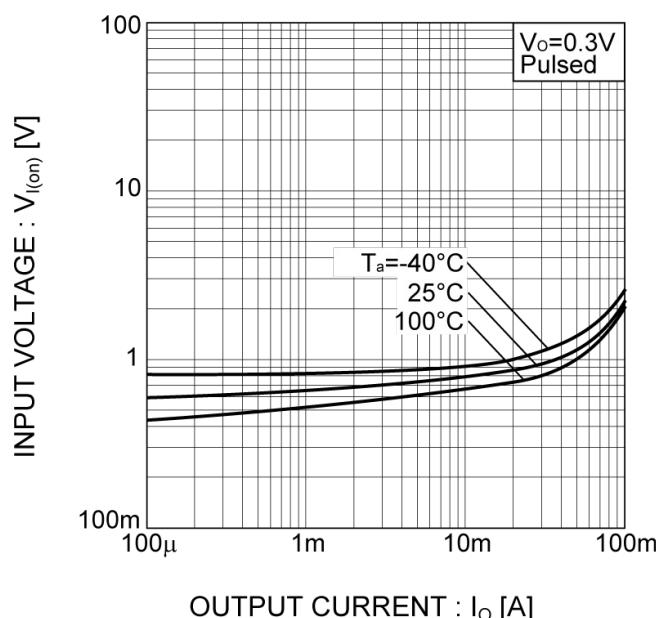


Fig.2 Output current vs. input voltage (OFF characteristics)

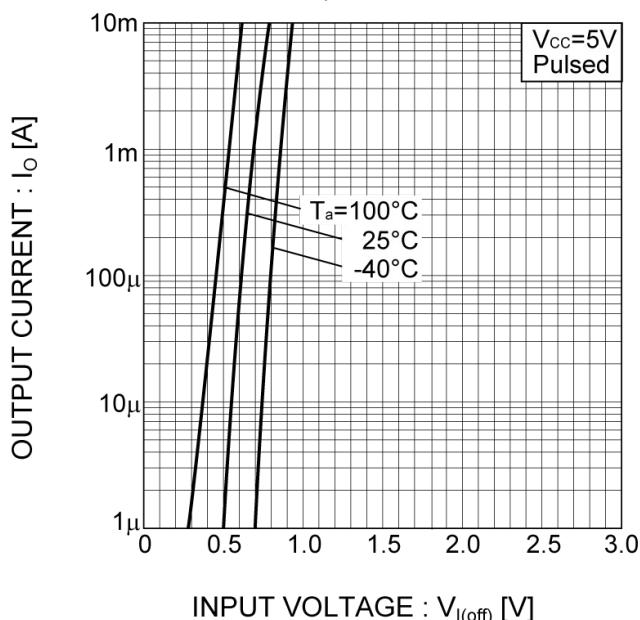


Fig.3 Output current vs. output voltage

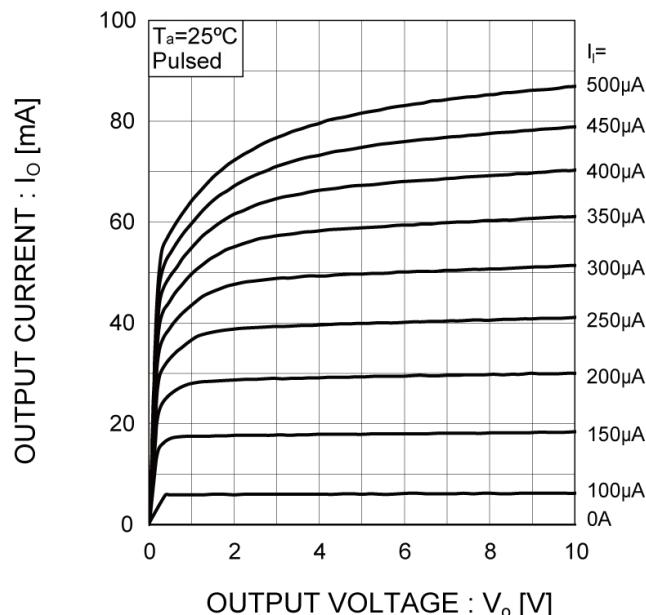


Fig.4 DC current gain vs. output current

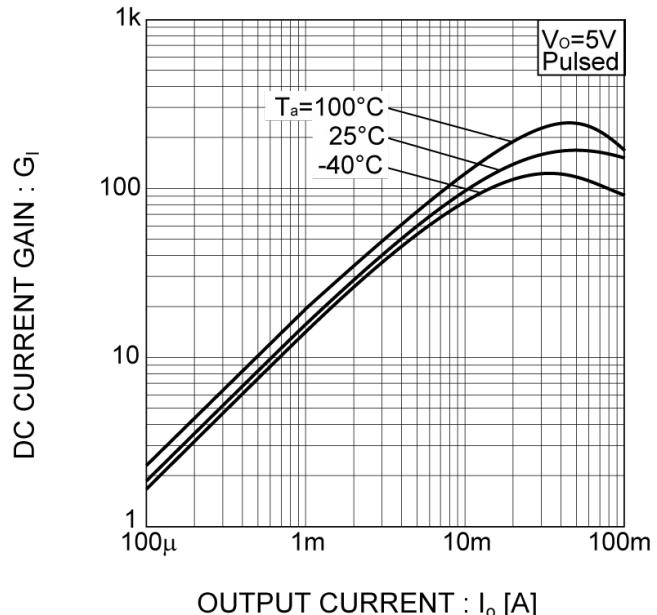
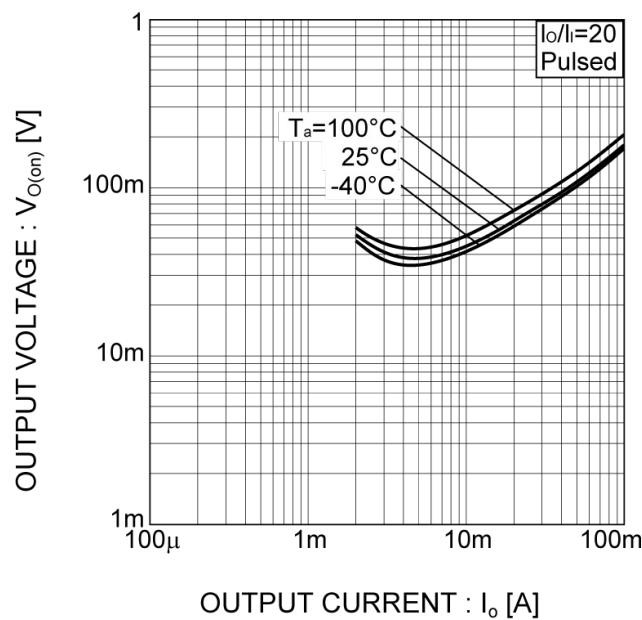
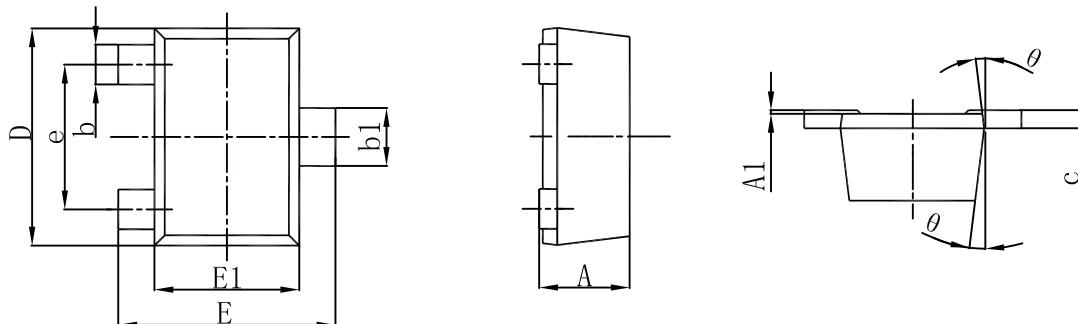


Fig.5 Output voltage vs. output current

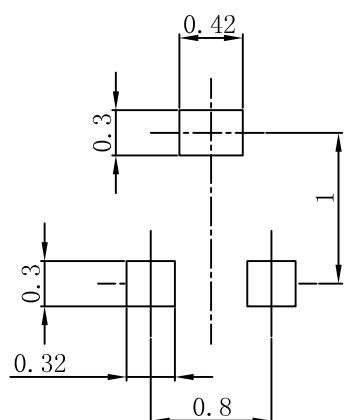


### SOT-723 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.450	0.550	0.018	0.022
A1	0.000	0.050	0.000	0.002
b	0.170	0.270	0.007	0.011
b1	0.270	0.370	0.011	0.015
c	0.080	0.150	0.003	0.006
D	1.150	1.250	0.045	0.049
E	1.150	1.250	0.045	0.049
E1	0.750	0.850	0.030	0.033
e	0.800TYP.		0.031TYP.	
θ	7° REF.		7° REF.	

### SOT-723 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.